NSN 5962-01-372-1263

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View Online at https://aerobasegroup.com/nsn/5962-01-372-1263 **Body Length:** 1.250 inches **Body Width:** Between 0.350 inches and 0.410 inches **Body Height:** 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** W/enable and w/reset and monolithic and w/disable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 15 input **Case Outline Source And Designator:** D-11 mil-m-38510 **Current Rating Per Characteristic:** 170.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Fifo buffer memory Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 54.00 nanoseconds propagation delay time, high to low level output and 68.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** First-in first-out **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:**

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N/a

24 printed circuit Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0